# NSN 5961-01-250-0444

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Inclosure	Matorial
inclosure	material:

Metal

**Overall Length:** 

0.260 inches

## Terminal Length:

1.500 inches

## **Overall Diameter:**

0.370 inches

### Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-5

### **Mounting Method:**

Terminal

### Terminal Circle Diameter:

0.200 inches

### **Features Provided:**

Hermetically sealed case

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

15.0 collector to base voltage, dc and 15.0 collector to emitter voltage, dc and 2.0 emitter to base voltage, dc

## **Current Rating Per Characteristic:**

1.00 microamperes zero-gate-voltage source current absolute

## Power Rating Per Characteristic:

150.0 milliwatts small-signal input power, common-collector preset

### **Transfer Ratio:**

30.0 static forward current transfer ratio, common-emitter and 200.0 static forward current transfer ratio, common-emitter

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

### **Special Features:**

Junction pattern arrangement: npn

### **Terminal Type And Quantity:**

3 uninsulated wire lead

### Shelf Life:

N/a

### Unit Of Measure:

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## Demilitarization:

No

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